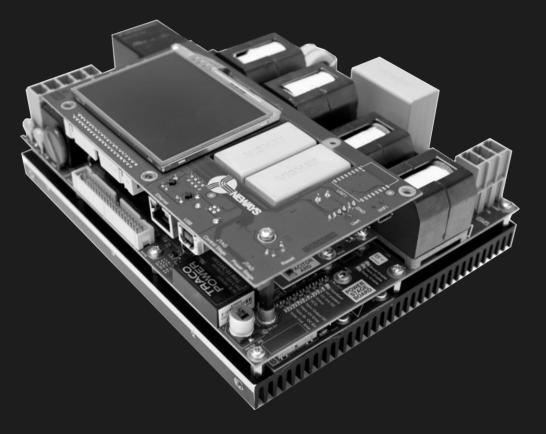
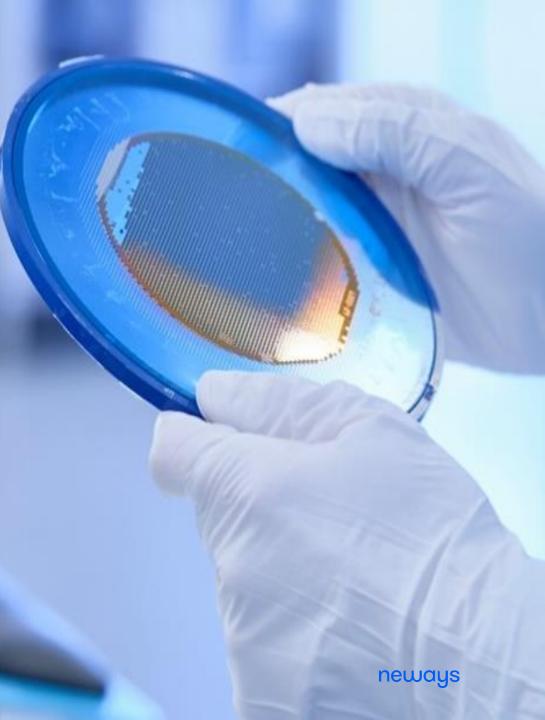


Technology development @ Neways -Use case: GaN PV inverter



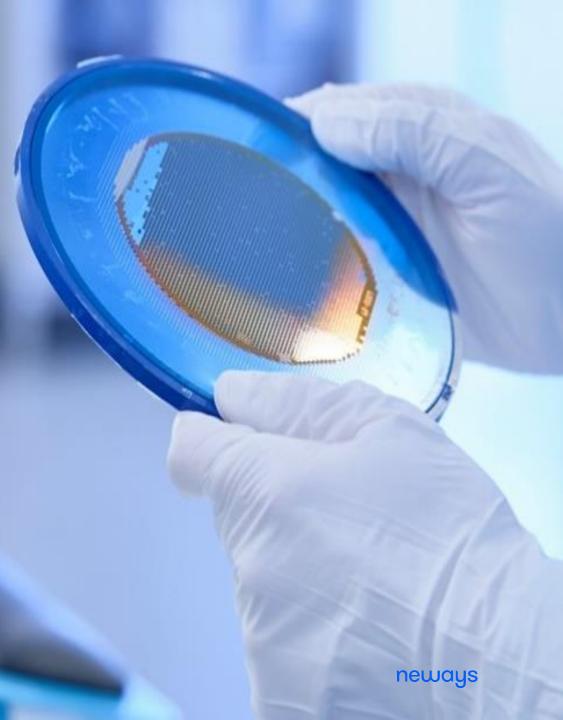
February 29th, 2024

- ► Neways at a glance
- Development and engineering
- ► Use case: GaN PV inverter



► Neways at a glance

- Development and engineering
- ► Use case: GaN PV inverter



Neways as international innovator

International technology partner

With more than **50 years'** experience combined with worldclass engineering power, Neways develops and produces electronics, facilitating disruptive technological innovations in high growth industries Driving innovation in high-growth industries



Smart mobility



Semicon solutions

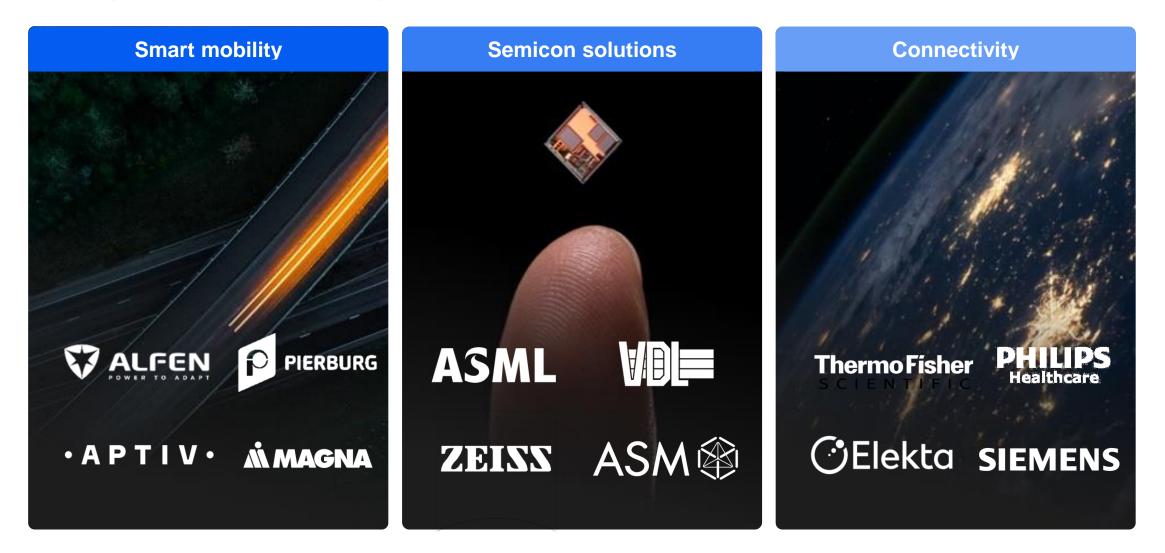


Connectivity

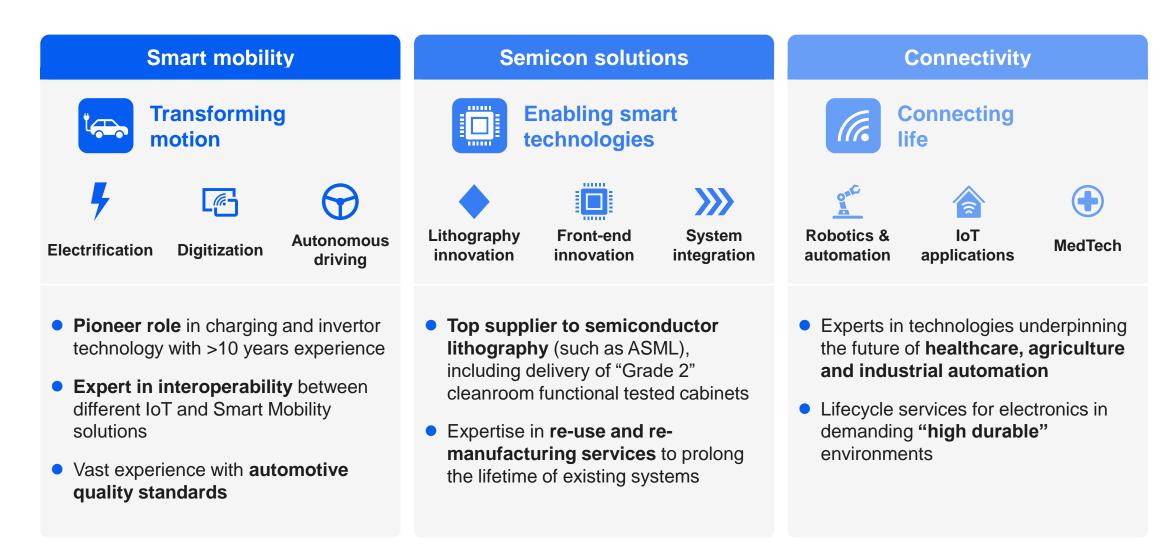
€470m 2021 revenue

>2,600 Employees **18%** Engineers in workforce

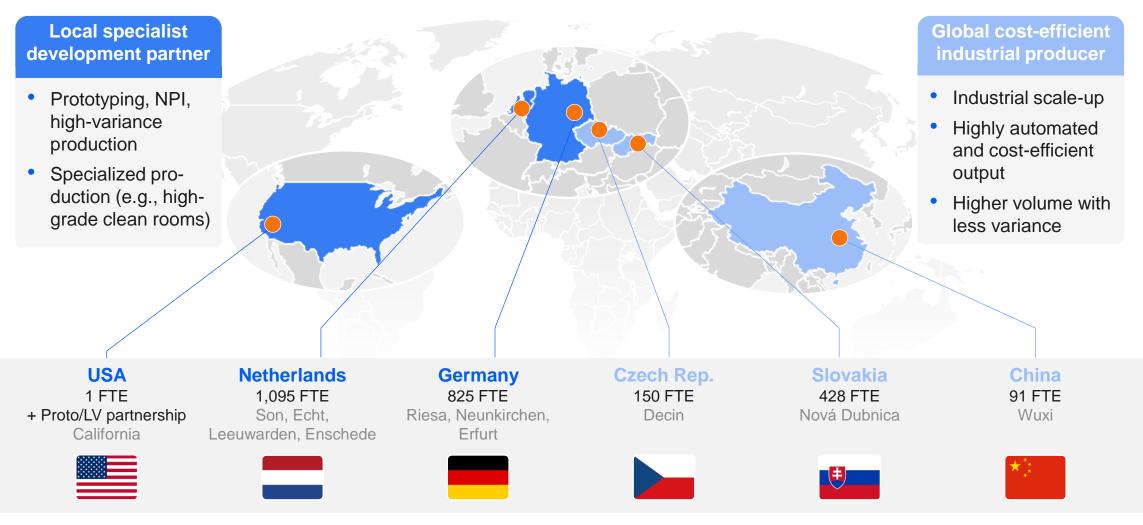
Leading in electronics for a sustainable future, and serving the most demanding customers



Firmly positioned across our three business lines



Footprint to optimally cater to our customers' local needs and enable cost-efficient industrial scale-up globally



neways

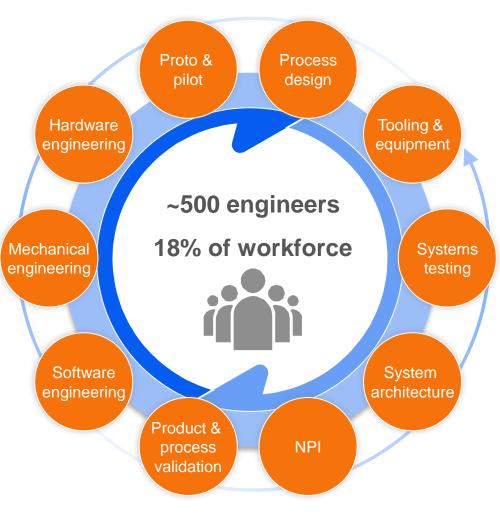
Our skilled engineers enable our value-adding technology proposition...

We integrate your requirements as you need it with close connection to production

New technology development

Developing **new technologies** addressing **future trends**, optimizing for **availability** and **circularity** with ability to quickly respond to **market dynamics** and **cross-industry innovation**

Based in our innovation centers in the Netherlands (Son, Echt and Enschede) and Germany (Erfurt) –setting up innovation hub in Romania



Process & production engineering

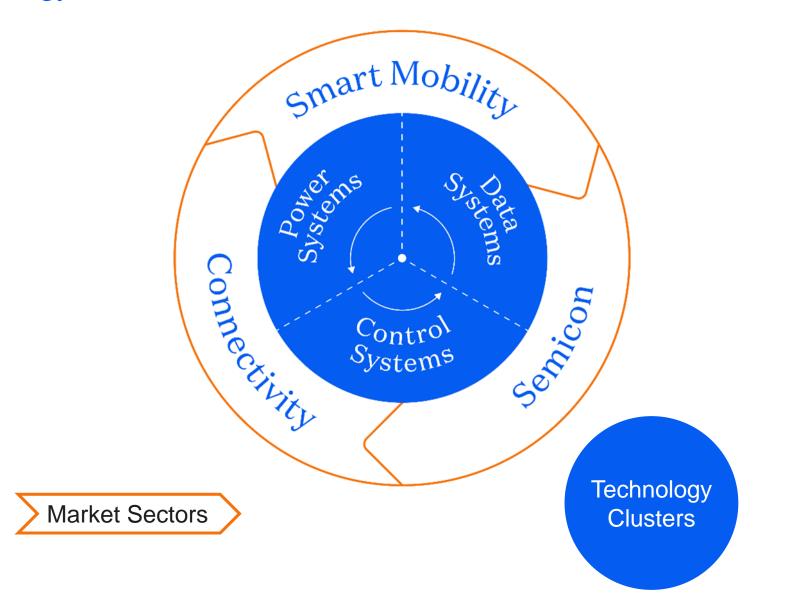
Optimizing design and production processes, for example for new product introductions, industrial scaleup and designing products for circularity

Integrated in our various production locations across the Netherlands, Germany, the Czech Republic, Slovakia, and China

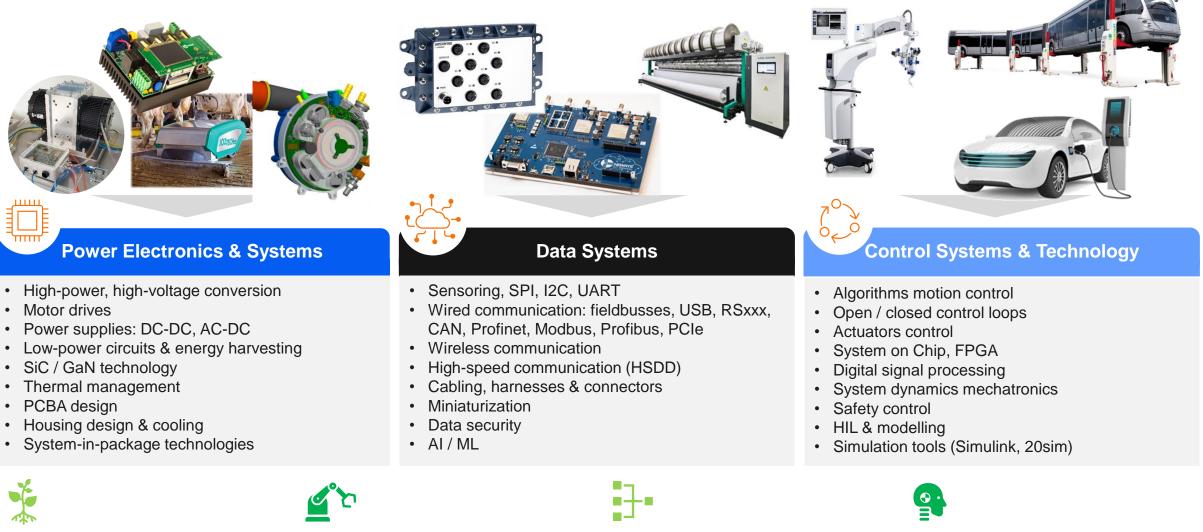
- ► Neways at a glance
- Development and engineering
- ► Use case: GaN PV inverter

Neways Technologies (NT) –

Three technology clusters connected with all 3 Market Sectors



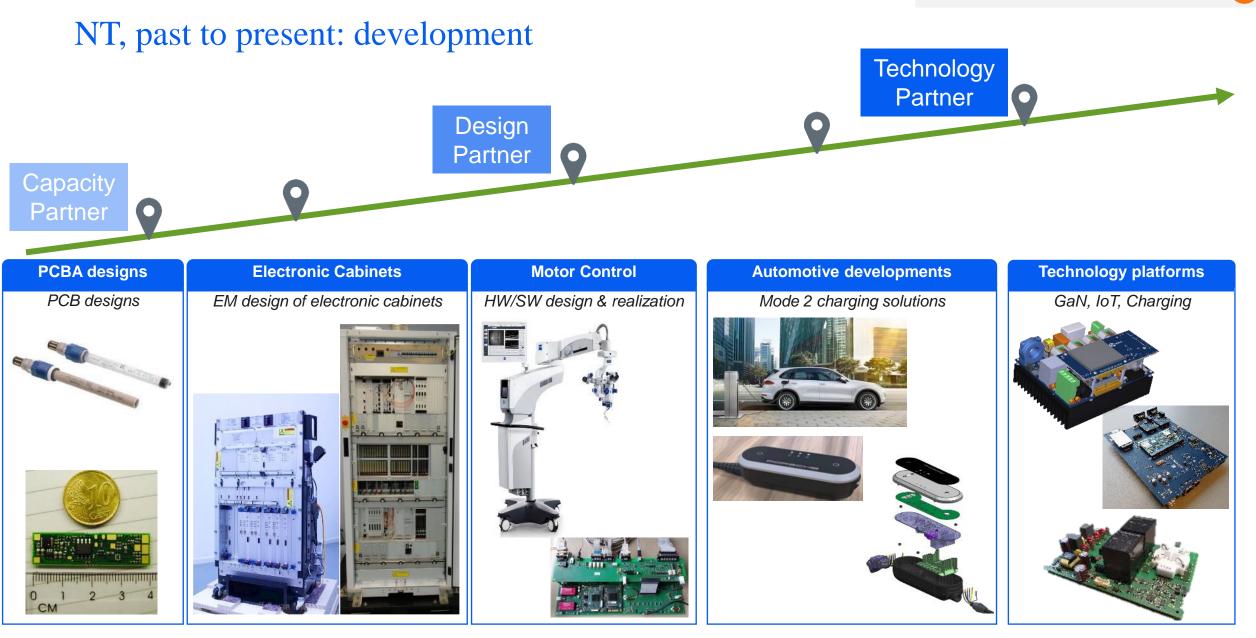
Technology clusters, for which Neways is recognized for



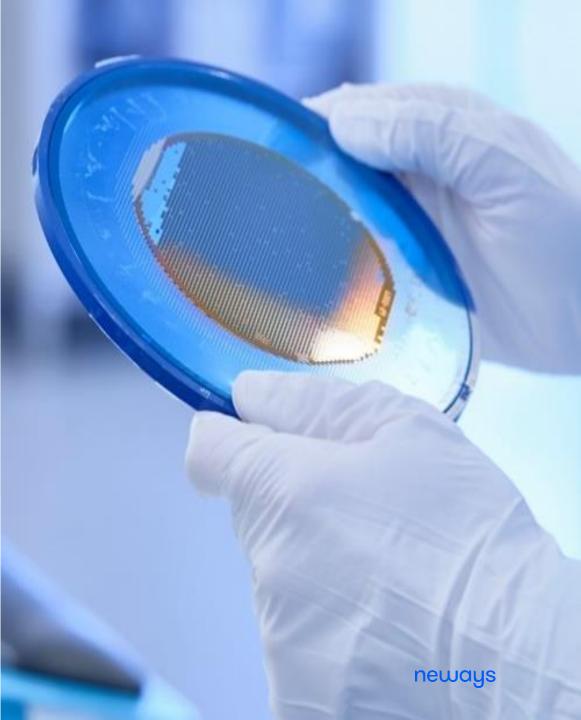
TECHNOLOGIES

Design for Sustainability





- ► Neways at a glance
- Development and engineering
- Use case: GaN PV inverter (technology demonstrator)



Neways as sustainable development partner

GaN

Design for sustainability topic examples:

- Serviceability
- Predictive maintenance
- Reuse of materials
 - Increase efficiency
- Use less materials

...





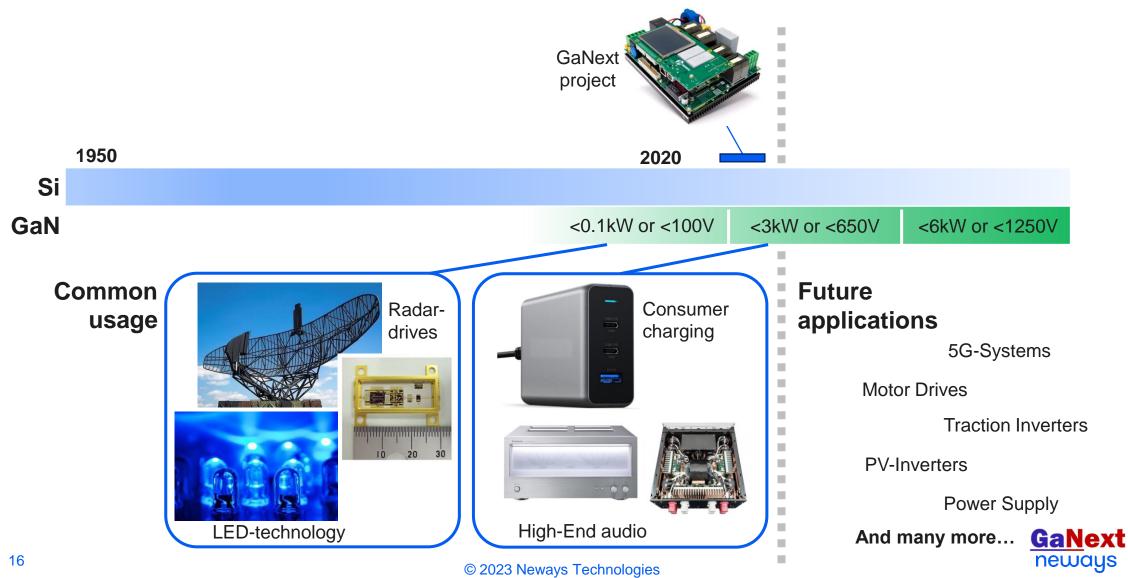
Introduction: GaN and GaNext

- Gallium Nitride (GaN) in power applications
 - Wide-bandgap semiconductor
 - Faster switching speeds (compared to Si)
 - Higher conversion efficiencies and power densities
 - Disadvantages: cost, reliability, EMC, implementation effort
- GaNext project
 - Remove barriers to adoption of GaN
 - Demonstrate higher efficiency and power density for power applications
 - Develop intelligent GaN power module
 - Integrate/co-package power device with drive, voltage control, and protection circuits

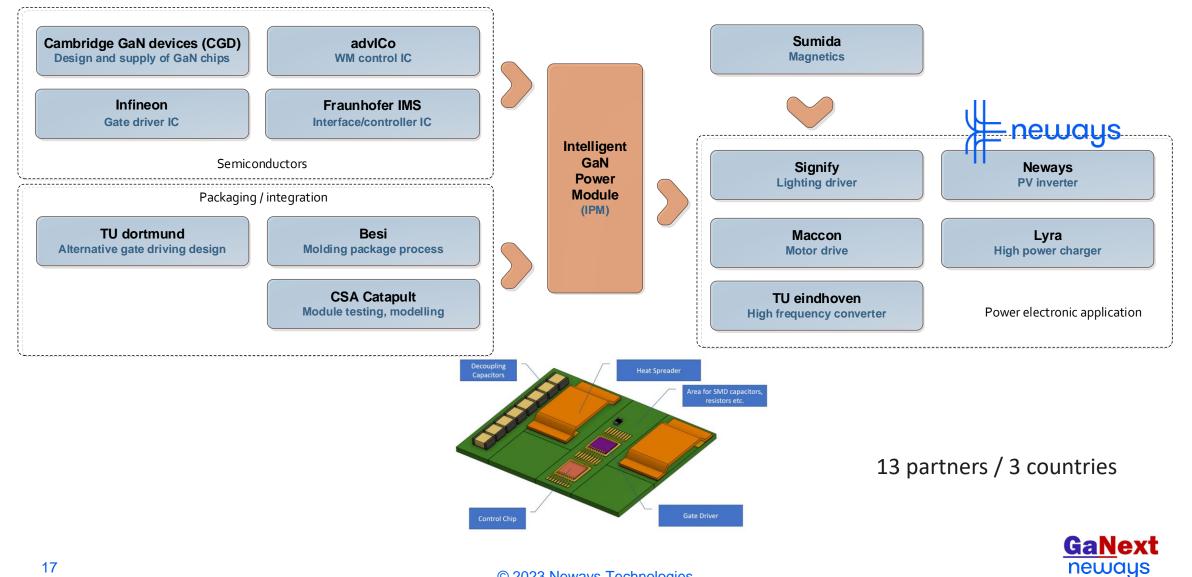




Transitioning from <0.1kW/<100V into 3kW/650V \rightarrow opening new application areas in automotive and industrial



GaNext: project and positioning of Neways



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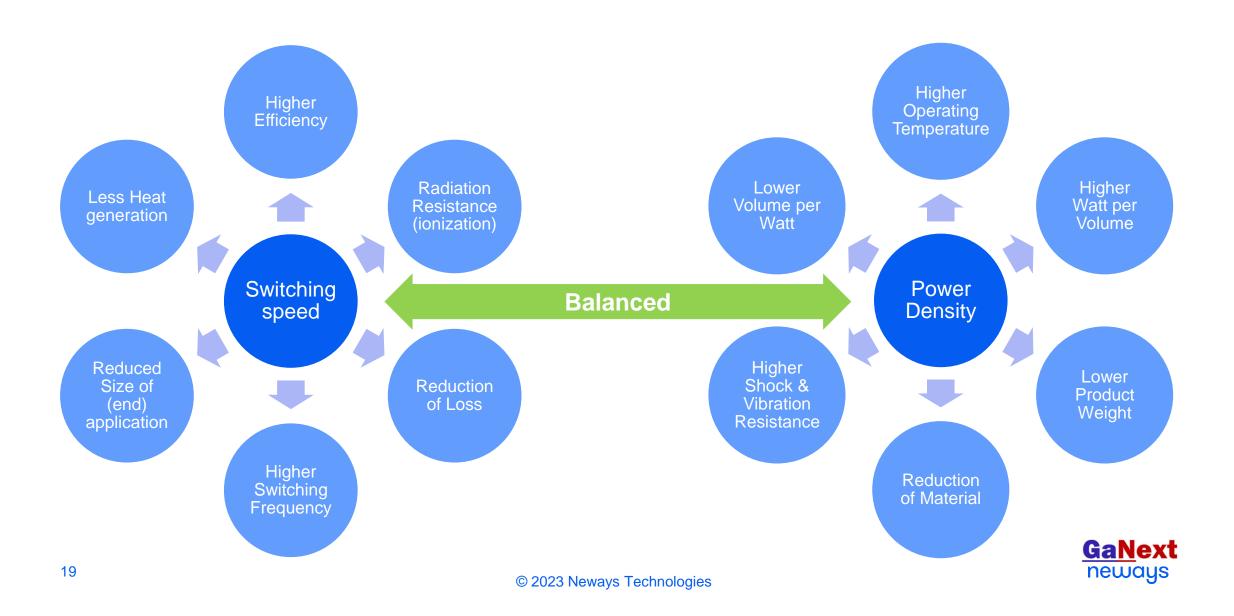
Neways GaNext PV inverter

- Vin 150-350VDC, Vout 230VAC
- Maximum output power: 3kW
- Switching frequency selected for optimum size vs. efficiency
- Transformer-less design
- Power density target: 1kW/L including housing
- Switching frequency: 350kHz
- Uses CGD GaN HEMTs in:
 - Boost converter stage
 - Output stage
- GaNext Intelligent Power Modules (IPM) used in output stage of improved power inverter





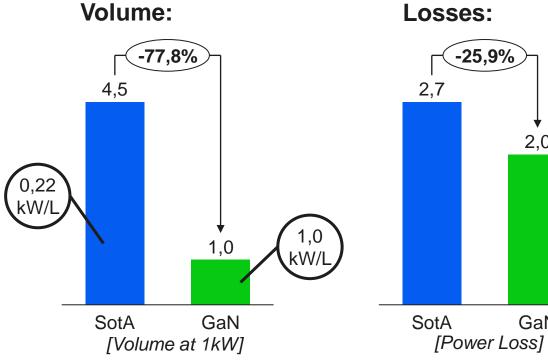
Advantages of using GaN. What is important to you?

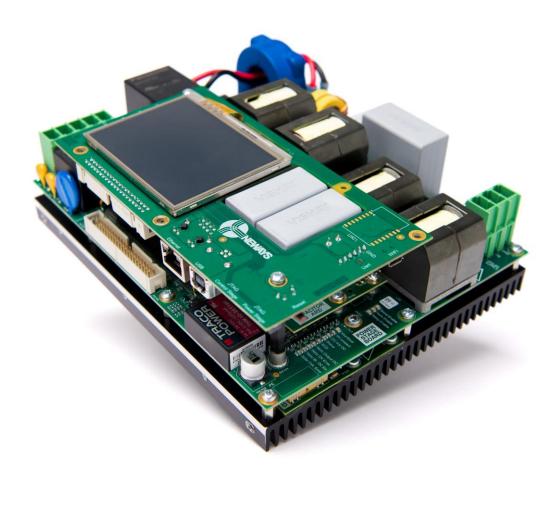


GaNext: GaN-based PV inverter with optimized efficiency and reduced size

Key Achievements:

- Successful deployment of GaN-technology •
- **Optimized Size vs Efficiency**
- Achieved Power density: 1kW/L including housing .
- Realized transformer-less design .





GaNext neways

GaN

2,0

Neways has the expertise and knowledge to successfully implement improved GaN-technologies, enabling great advantages in high-power and high-voltage applications

The GaN technology sets the bar in power conversion with:

- Higher efficiency
 - Reduced heath dissipation
 - Smaller cooling measures
- Smaller product/module dimensions
 - Re-think system architectures
 - Deployment of power inverters in narrow spaces
 - Integrate power inverters into product enclosures
 - Improve sustainability
 - Less material needed
 - Smaller logistical impact

GaN challenges = Neways Key Expertise

- Thermal Management
 - GaN device
 - Driver circuitry
 - Bootstrap circuitry
- Gate Control
- Voltage derating
- EMI
- VDS 100-650V



